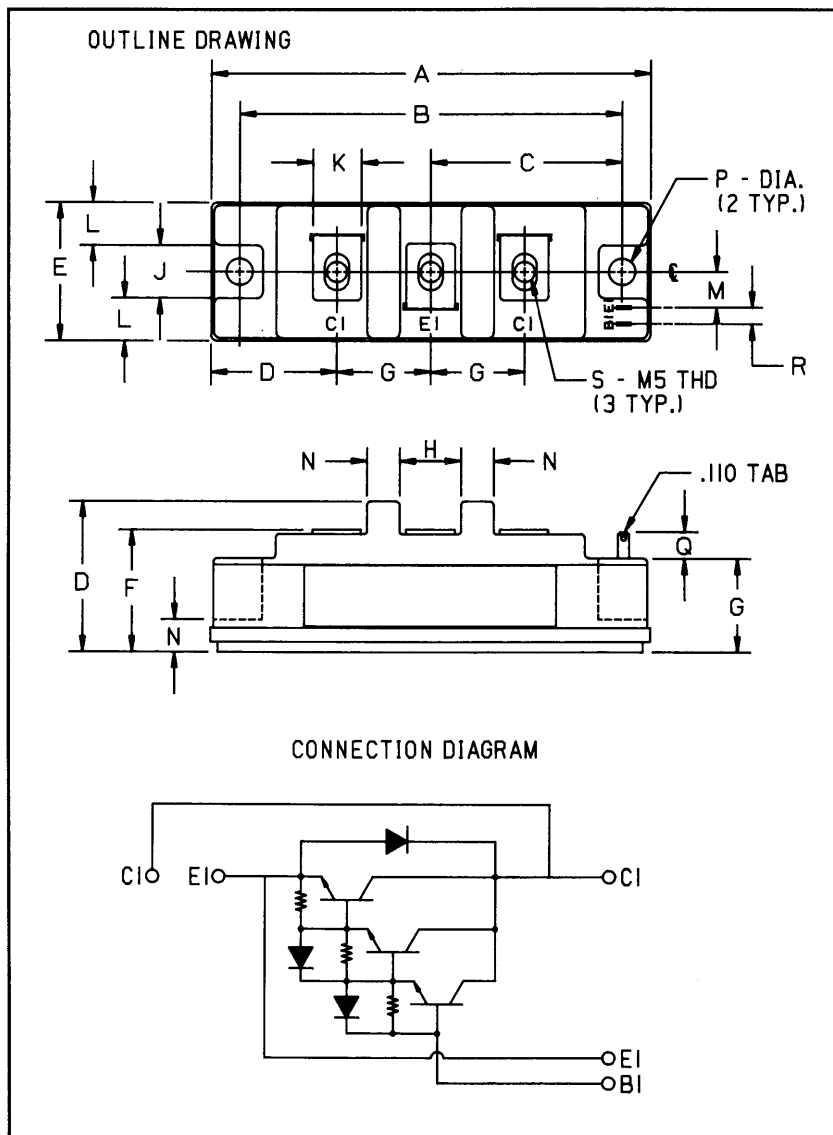


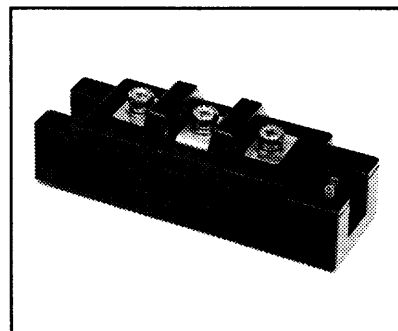
Single Darlington Transistor Module 150 Amperes/1000 Volts



Outline Drawing

Dimensions	Inches	Millimeters
A	4.252 Max.	108 Max.
B	3.661 ± 0.012	93 ± 0.3
C	1.831	46.5
D	1.457	37
E	1.339 Max.	34 Max.
F	1.181 Max.	30 Max.
G	0.906	23
H	0.591	15
J	0.512	13

Dimensions	Inches	Millimeters
K	0.472	12
L	0.413	10.5
M	0.344	8.75
N	0.315	8
P	0.256 Dia.	6.5 Dia.
Q	0.256 Min.	6.5 Min.
R	0.157	4
S	M5 Metric	M5



Description:

The Powerex Single Darlington Transistor Modules are high power devices designed for use in switching applications. The modules are isolated, consisting of one Darlington Transistor with a reverse parallel connected high-speed diode and base-to-emitter speed-up diode.

Features:

- ☐ Isolated Mounting
- ☐ Planar Chips
- ☐ Discrete Fast Recovery Feedback Diode
- ☐ High Gain (h_{FE})
- ☐ TAB Quick-Connect Terminals
- ☐ Base-Emitter Speed-up Diode

Applications:

- ☐ Inverters
- ☐ DC Motor Control
- ☐ Switching Power Supplies
- ☐ AC Motor Control

Ordering Information:

Example: Select the complete eight digit module part number you desire from the table - i.e. KS221K15 is a 1000 Volt, 150 Ampere Single Darlington Module.

Type	$V_{CE0(sus)}$ Volts (1000)	Current Rating Amperes (X 10)
KS22	1K	15



Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (412) 925-7272

KS221K15
Single Darlington Transistor Module
 150 Amperes/1000 Volts

Absolute Maximum Ratings, $T_j = 25^\circ\text{C}$ unless otherwise specified

Ratings	Symbol	KS221K15	Units
Junction Temperature	T_j	-40 to 150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-40 to 125	$^\circ\text{C}$
Collector-Emitter Sustaining Voltage, $V_{BE} = -2\text{V}$	$V_{CEV(sus)}$	1000	Volts
Collector-Base Voltage	V_{CBO}	1000	Volts
Emitter-Base Voltage	V_{EBO}	7	Volts
Collector-Emitter Voltage	V_{CEV}	1000	Volts
Continuous Collector Current	I_C	150	Amperes
Diode Forward Current	I_{FM}	150	Amperes
Continuous Base Current	I_B	8	Amperes
Diode Surge Current	I_{FSM}	1500	Amperes
Power Dissipation	P_t	1000	Watts
Max. Mounting Torque M5 Terminal Screws	—	17	in.-lb.
Max. Mounting Torque M6 Mounting Screws	—	26	in.-lb.
Module Weight (Typical)	—	250	Grams
V Isolation	V_{RMS}	2500	Volts

Electrical Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

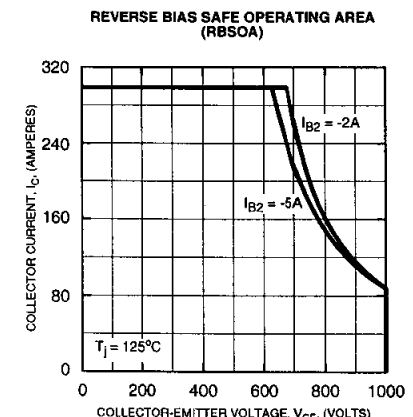
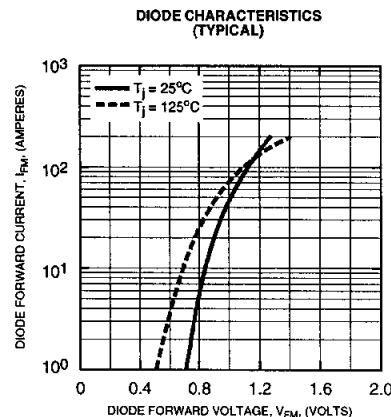
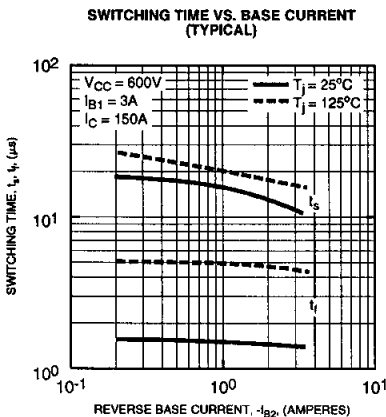
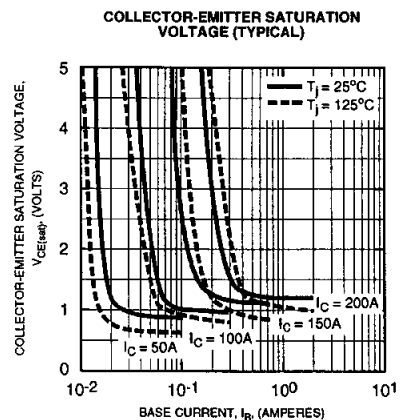
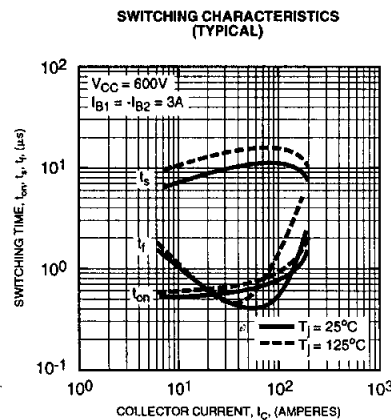
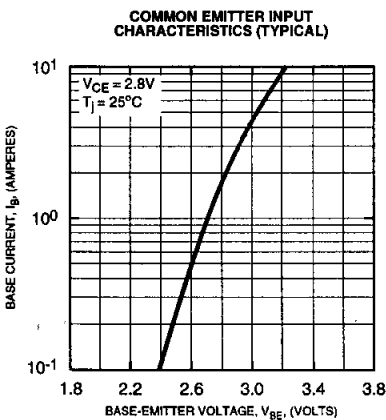
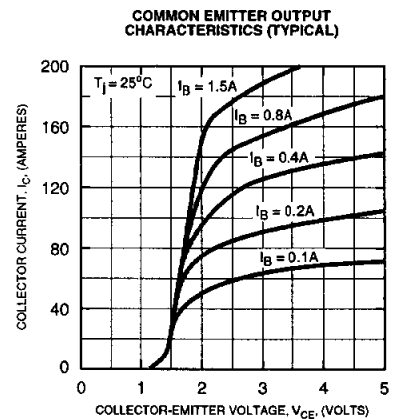
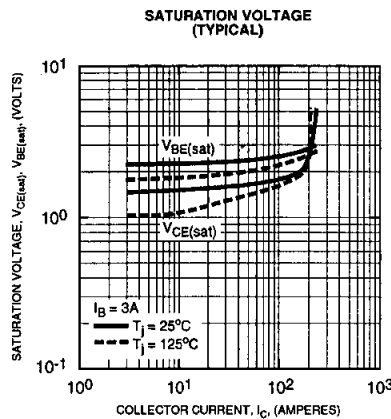
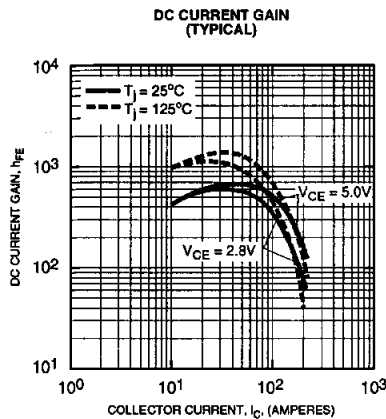
Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Collector Cutoff Current	I_{CEV}	$V_{CE} = 1000\text{V}, V_{BE} = -2\text{V}$	—	—	2	mA
		$V_{CE} = 1000\text{V}, V_{BE} = -2\text{V}, T_C = 125^\circ\text{C}$	—	—	20	mA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = 7\text{V}$	—	—	400	mA
DC Current Gain	h_{FE}	$I_C = 150\text{A}, V_{CE} = 5\text{V}$	100	—	—	—
Diode Forward Voltage	V_{FM}	$I_{FM} = 150\text{A}$	—	—	1.8	Volts
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 150\text{A}, I_B = 2\text{A}$	—	—	2.5	Volts
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = 150\text{A}, I_B = 2\text{A}$	—	—	3.5	Volts
Resistive	Turn-on	t_{on}	$V_{CC} = 600\text{V}$	—	—	3.0 μs
Load	Storage Time	t_s	$I_C = 150\text{A}$	—	—	15 μs
Switch Times	Fall Time	t_f	$I_{B1} = 2\text{A}, I_{B2} = -2\text{A}$	—	—	3.0 μs

Thermal and Mechanical Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance, Case-to-Sink	$R_{\theta(c-s)}$	—	—	—	0.13	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Case	$R_{\theta(j-c)}$	Transistor Part	—	—	0.125	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Case	$R_{\theta(j-c)}$	Diode Part	—	—	0.6	$^\circ\text{C/W}$

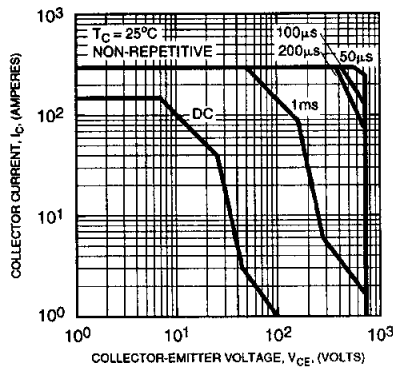
KS221K15

Single Darlington Transistor Module
150 Amperes/1000 Volts

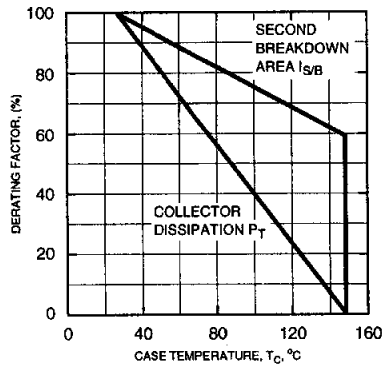


KS221K15
Single Darlington Transistor Module
 150 Amperes/1000 Volts

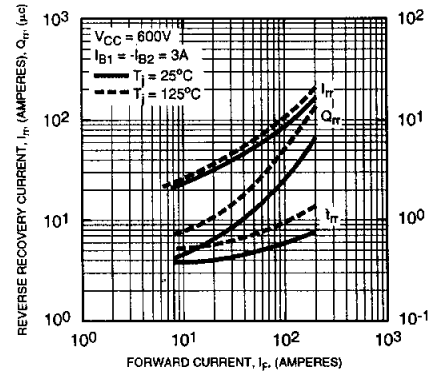
FORWARD BIAS SAFE OPERATING AREA (SOA)



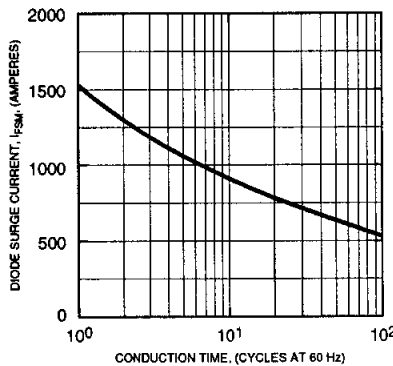
DERATING FACTOR OF SAFE OPERATING AREA (SOA)



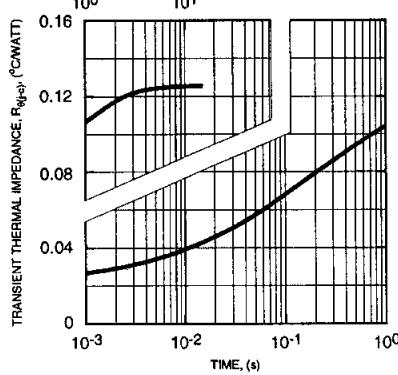
REVERSE RECOVERY CHARACTERISTICS OF FREE-WHEEL DIODE (TYPICAL)



DIODE FORWARD SURGE CURRENT



TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (TRANSISTOR)



TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (DIODE)

